

# ACMSP2303T-HF

P-Channel  
RoHS Device  
Halogen Free



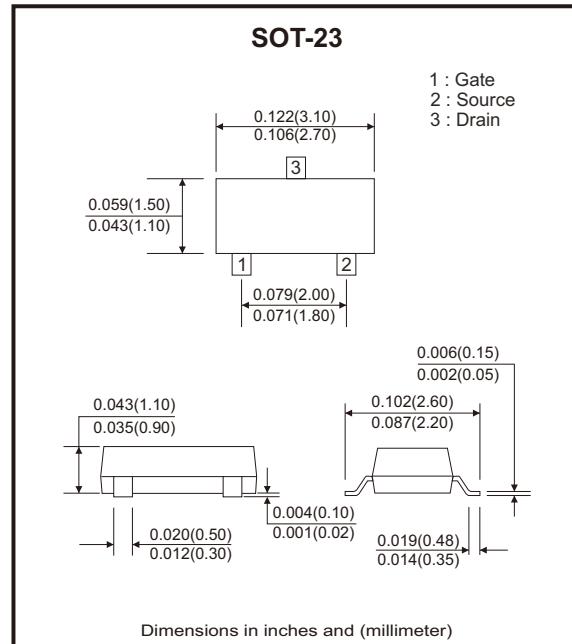
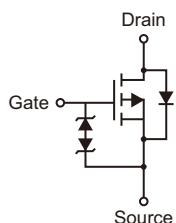
## Features

- Electrostatic sensitive devices.
- $V_{DS}$  (V) = -30V.
- $I_D$  = -2.7A ( $V_{GS}$  = -10V)
- $R_{DS(ON)} < 190\text{m}\Omega$  ( $V_{GS}$  = -10V)  
 $R_{DS(ON)} < 330\text{m}\Omega$  ( $V_{GS}$  = -4.5V)
- AEC-Q101 Qualified.

## Mechanical data

- Case: SOT-23, molded plastic.

## Circuit Diagram



## Maximum Ratings (at $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	$V_{DSS}$	-30	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	V
Continuous drain current	$I_D$	-2.7 -2.2	A
Pulsed drain current	$I_{DM}$	-10	A
Power dissipation	$P_D$	2.3 1.5 1.0 0.7	W
Thermal resistance, junction to ambient	$R_{\theta JA}$	120	$^\circ\text{C}/\text{W}$
Junction and storage temperature range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** (at  $T_a=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Static Parameters</b>						
Drain-source breakdown voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = -250\mu\text{A}$	-30			V
Zero gate voltage drain current	$I_{\text{DS}}^{\text{SS}}$	$V_{\text{DS}} = -30\text{V}, V_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
Gate-body leakage	$I_{\text{GSS}}$	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 20\text{V}$			$\pm 100$	nA
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250\mu\text{A}$	-1		-3	V
On-state drain current	$I_{\text{D}(\text{on})}$	$V_{\text{DS}} = -5\text{V}, V_{\text{GS}} = -10\text{V}$	-10			A
Static drain-source on resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -10\text{V}, I_{\text{D}} = -1.9\text{A}$		158	190	$\text{m}\Omega$
		$V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -1.4\text{A}$		275	330	
Drain-source diode forward voltage	$V_{\text{SD}}$	$I_{\text{S}} = -1.5\text{A}, V_{\text{GS}} = 0\text{V}$		-0.8	-1.2	V
Forward transconductance	$g_{\text{FS}}$	$V_{\text{DS}} = -5\text{V}, I_{\text{D}} = -1.9\text{A}$		2		S
Max. body-diode continuous current	$I_{\text{S}}$				-1.75	A
<b>Dynamic Characteristics</b>						
Input capacitance	$C_{\text{iss}}$	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = -15\text{V}, f = 1\text{MHz}$		155		pF
Output capacitance	$C_{\text{oss}}$			35		
Reverse transfer capacitance	$C_{\text{rss}}$			25		
Gate resistance	$R_{\text{G}}$	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 0\text{V}, f = 1\text{MHz}$		4	8	$\Omega$
<b>Switching Characteristics</b>						
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -15\text{V}, R_{\text{L}} = 10\Omega, I_{\text{DS}} = -1.5\text{A}, V_{\text{GEN}} = -10\text{V}, R_{\text{G}} = 1\Omega$		4	8	nS
Rise time	$t_{\text{r}}$			11	18	
Turn-off delay time	$t_{\text{d}(\text{off})}$			11	18	
Fall time	$t_{\text{f}}$			8	18	
Total gate charge	$Q_{\text{g}}$	$V_{\text{GS}} = -15\text{V}, V_{\text{DS}} = -10\text{V}, I_{\text{D}} = -1.9\text{A}$		15.5	22	nC
		$V_{\text{GS}} = -15\text{V}, V_{\text{DS}} = -4.5\text{V}, I_{\text{D}} = -1.9\text{A}$		2	4	
Gate-source charge	$Q_{\text{gs}}$			0.6		
Gate-drain charge	$Q_{\text{gd}}$			1		
Body diode reverse recovery time	$t_{\text{rr}}$	$I_{\text{F}} = -1.5\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		17	26	nS
Body diode reverse recovery charge	$Q_{\text{rr}}$			7		nC

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## Rating and Characteristic Curves (ACMSP2303T-HF)

Fig.1 - Output Characteristics

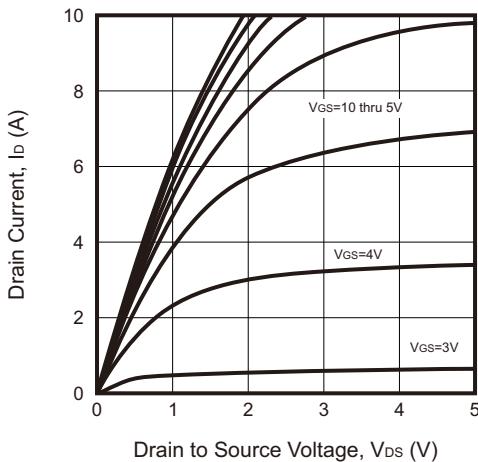


Fig.2 - Transfer Characteristics

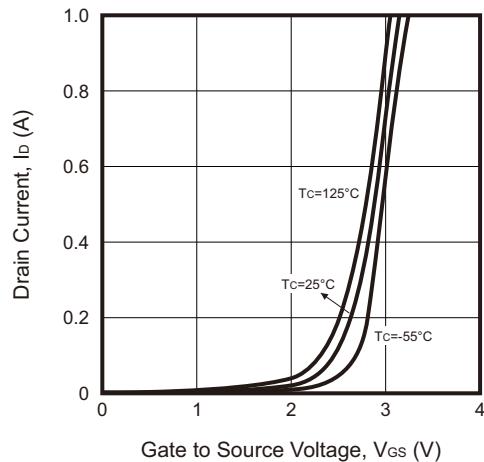


Fig.3 - On-Resistance vs. Drain Current and Gate Voltage

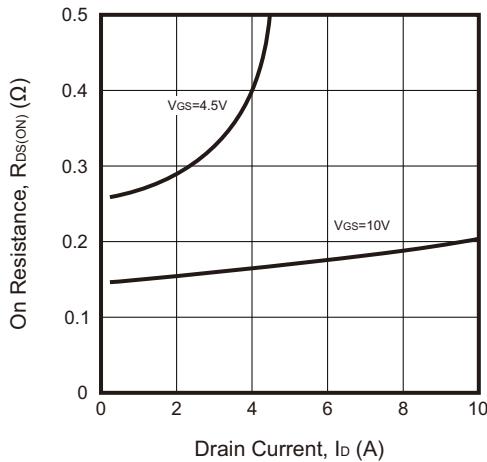


Fig.4 - Capacitance

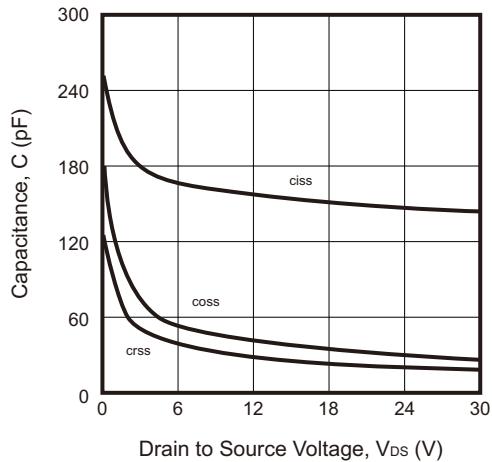


Fig.5 - Gate Charge

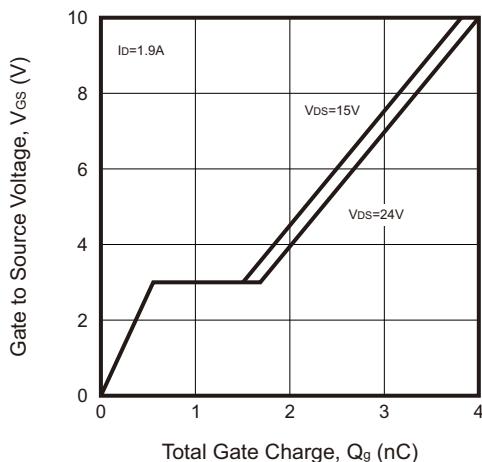
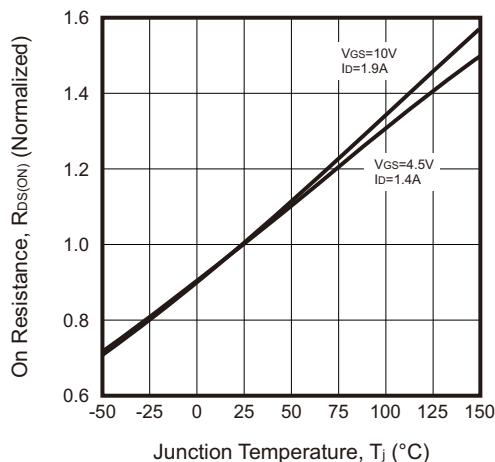


Fig.6 - On-Resistance vs. Junction Temperature



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## Rating and Characteristic Curves (ACMSP2303T-HF)

Fig.7 - Source Drain Diode Forward Voltage

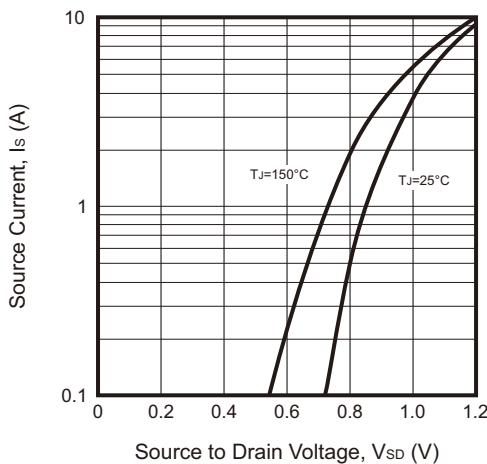


Fig.8 - On-Resistance vs. Gate to Source Voltage

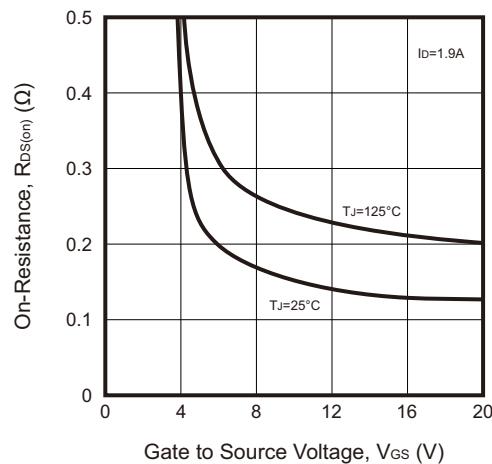


Fig.9 - Threshold Voltage

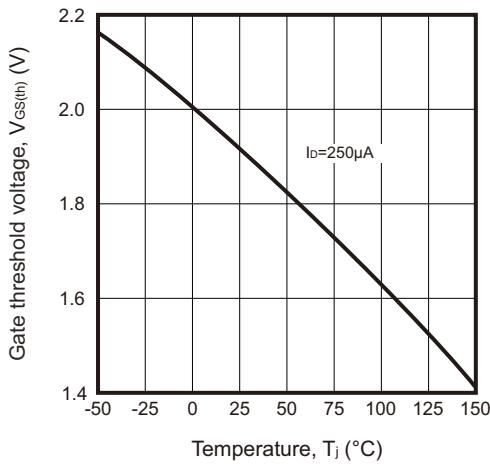
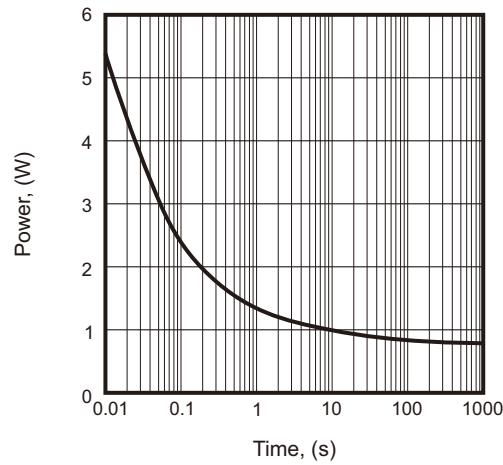
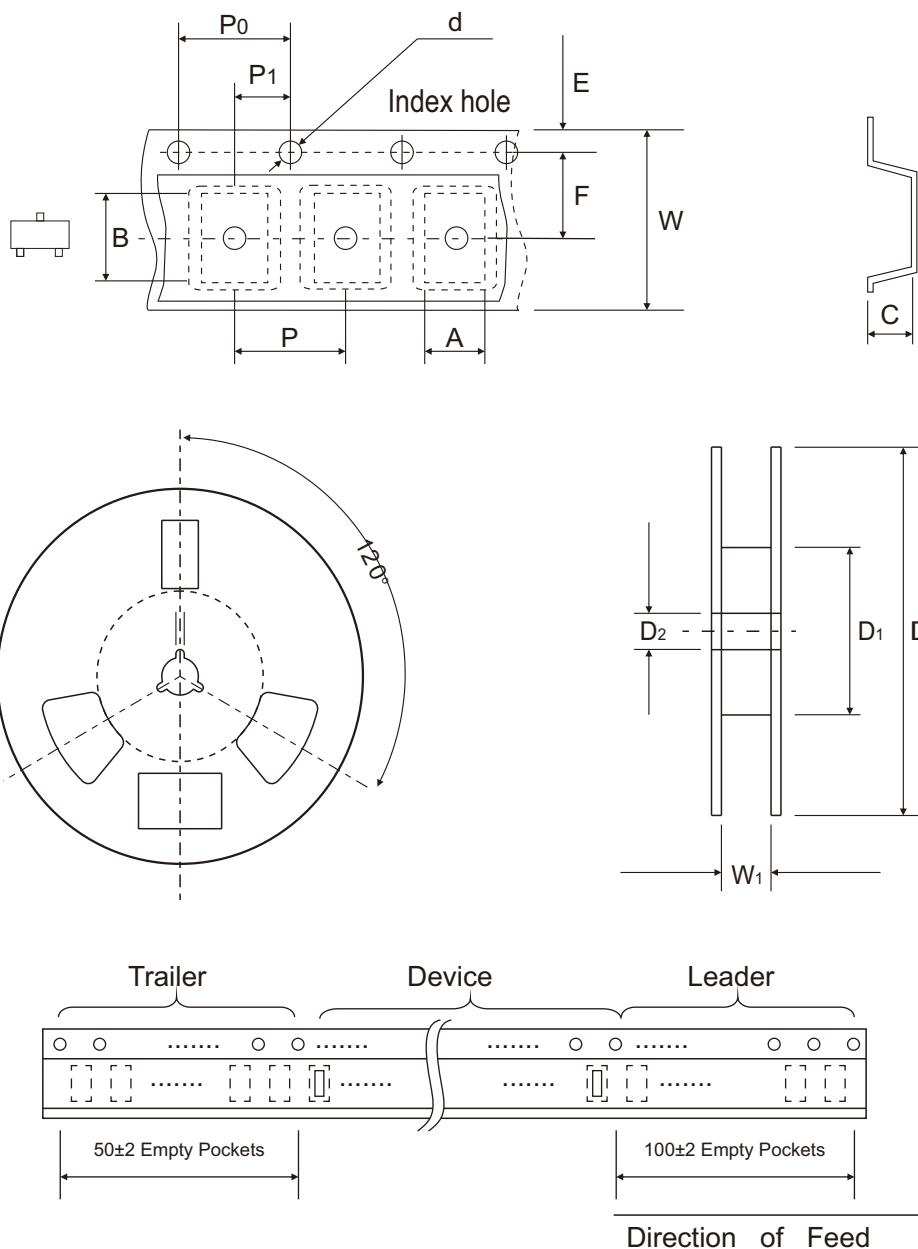


Fig.10 - Single Pulse Power



## Reel Taping Specification



	SYMBOL	A	B	C	d	D	D1	D2
SOT-23	(mm)	$3.15 \pm 0.10$	$2.77 \pm 0.10$	$1.22 \pm 0.10$	$1.50 \pm 0.10$	$178.00 \pm 1.00$	$54.00 \pm 0.50$	$13.00 \pm 0.50$
SOT-23	(inch)	$0.124 \pm 0.004$	$0.109 \pm 0.004$	$0.048 \pm 0.004$	$0.059 \pm 0.004$	$7.008 \pm 0.039$	$2.126 \pm 0.020$	$0.512 \pm 0.020$

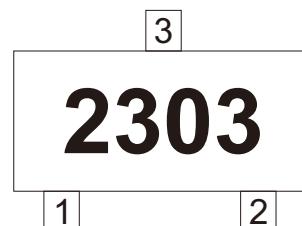
	SYMBOL	E	F	P	P0	P1	W	W1
SOT-23	(mm)	$1.75 \pm 0.10$	$3.50 \pm 0.05$	$4.00 \pm 0.10$	$4.00 \pm 0.10$	$2.00 \pm 0.05$	$8.00 \pm 0.30$ -0.10	$9.50 \pm 1.00$
SOT-23	(inch)	$0.069 \pm 0.004$	$0.138 \pm 0.002$	$0.157 \pm 0.004$	$0.157 \pm 0.004$	$0.079 \pm 0.002$	$0.315 \pm 0.012$ -0.004	$0.374 \pm 0.039$

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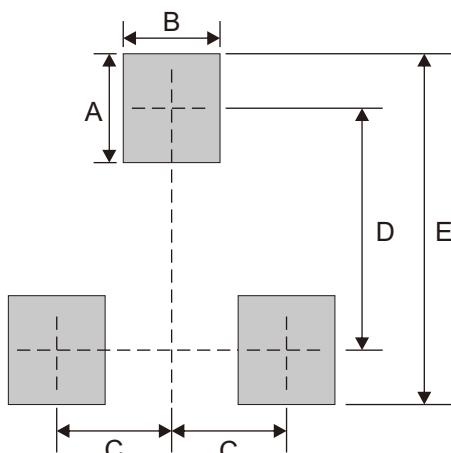
## Marking Code

Part Number	Marking Code
ACMSP2303T-HF	2303



## Suggested PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.90	0.035
B	0.80	0.031
C	0.95	0.037
D	2.00	0.079
E	2.90	0.114



Note: 1. The pad layout is for reference purposes only.

## Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23	3,000	7